

CMOS Digital Integrated Circuits Silicon Monolithic

TC7SZ07FE

1. Functional Description

· Non-Inverter (Open Drain)

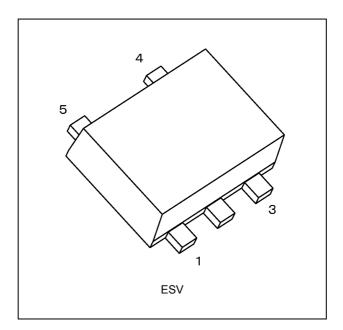
2. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 2)
- (3) High output current: ± 24 mA (min) at $V_{CC} = 3.0$ V
- (4) Super high speed operation: $t_{PZL} = 2.3 \text{ ns}$ (typ.) at $V_{CC} = 5.0 \text{ V}$, $C_L = 50 \text{ pF}$
- (5) Operation voltage range: $V_{CC} = 1.65$ to 5.5 V
- (6) 5.5 V tolerant inputs
- (7) 5.5 V power down protection output
- (8) Matches the performance of TC74LCX series when operated at $3.3\ V\ V_{CC}$

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

Note 2: For devices with the ordering part number ending in J(CT. T_{opr} = -40 to 85 °C for the other devices.

3. Packaging

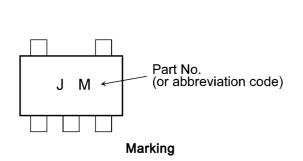


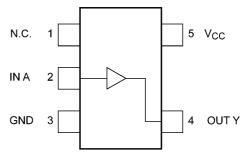
Start of commercial production

Downloaded from Arrow.com.



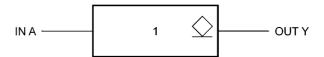
4. Marking and Pin Assignment





Pin Assignment (Top view)

5. IEC Logic Symbol



6. Truth Table

А	Υ
L	L
Н	Z

Z: High impedance

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 6.0	V
Input voltage	V _{IN}		-0.5 to 6.0	٧
DC output voltage	V _{OUT}	(Note 1)	-0.5 to 6.0	٧
Input diode current	I _{IK}		-20	mA
Output diode current	I _{OK}	(Note 2)	-20	mA
DC output current	I _{OUT}		50	mA
V _{CC} /ground current	I _{CC}		±50	mA
Power dissipation	P_{D}		150	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: I_{OUT} absolute maximum rating must be observed.

Note 2: V_{OUT} < GND



8. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}		_	1.65 to 5.5	V
		(Note 1)	_	1.5 to 5.5	
Input voltage	V _{IN}		_	0 to 5.5	V
Output voltage	V _{OUT}		_	0 to 5.5	V
Operating temperature	T _{opr}	(Note 2)	_	-40 to 125	°C
		(Note 3)	_	-40 to 85	
Input rise and fall time	dt/dv		V_{CC} = 1.8 \pm 0.15 V, 2.5 \pm 0.2 V	0 to 20	ns/V
			$V_{CC} = 3.3 \pm 0.3 \text{ V}$	0 to 10	
			V_{CC} = 5.0 ± 0.5 V	0 to 5	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 1: Data retention only

Note 2: For devices with the ordering part number ending in J(CT.

Note 3: For devices except those with the ordering part number ending in J(CT.

9. Electrical Characteristics

9.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		1.65 to 1.95	$V_{CC} \times 0.75$	_	_	V
				2.3 to 5.5	V _{CC} × 0.7	_	_	
Low-level input voltage	V _{IL}	_		1.65 to 1.95	_	_	$V_{CC} \times 0.25$	V
				2.3 to 5.5	_	_	$V_{CC} \times 0.3$	
Low-level output voltage	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 100 μA	1.65	_	0.0	0.1	V
				2.3	_	0.0	0.1	
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 4 mA	1.65	_	0.08	0.24	
			I _{OL} = 8 mA	2.3	_	0.1	0.3	
			I _{OL} = 16 mA	3.0	_	0.15	0.4	
			I _{OL} = 24 mA	3.0	_	0.22	0.55	
			I _{OL} = 32 mA	4.5	_	0.22	0.55	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5	_	_	±5	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±1	μА
Power-OFF leakage current	I _{OFF}	V _{IN} or V _{OUT} = 5.5 V		0	_	_	1	μА
Quiescent supply current	I _{CC}	V _{IN} = 5.5 V or GND		5.5	_		2	μА



9.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		1.65 to 1.95	V _{CC} × 0.75	_	V
				2.3 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	V _{IL}	_		1.65 to 1.95	_	V _{CC} × 0.25	V
				2.3 to 5.5	_	$V_{CC} \times 0.3$	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IL}$	I _{OL} = 100 μA	1.65	_	0.1	V
				2.3		0.1	
				3.0		0.1	
				4.5		0.1	
			I_{OL} = 4 mA	1.65	_	0.24	
			I_{OL} = 8 mA	2.3	_	0.3	
			I _{OL} = 16 mA	3.0	_	0.4	
			I_{OL} = 24 mA	3.0	_	0.55	
			I _{OL} = 32 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5	_	±10	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±10	μΑ
Power-OFF leakage current	I _{OFF}	V _{IN} or V _{OUT} = 5.5 V		0		10	μΑ
Quiescent supply current	I _{CC}	V _{IN} = 5.5 V or GND		5.5	_	20	μΑ

9.3. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		1.65 to 1.95	V _{CC} × 0.75	_	V
				2.3 to 5.5	V _{CC} × 0.7	_	
Low-level input voltage	V _{IL}	_		1.65 to 1.95	_	$V_{CC} \times 0.25$	V
				2.3 to 5.5	_	$V_{CC} \times 0.3$	
Low-level output voltage	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 100 μA	1.65	_	0.1	V
				2.3	_	0.1	
				3.0	_	0.1	
				4.5	_	0.1	
			$I_{OL} = 4 \text{ mA}$	1.65	_	0.7	
			I_{OL} = 8 mA	2.3	_	0.45	
			I _{OL} = 16 mA	3.0	_	0.6	
			I _{OL} = 24 mA	3.0	_	0.8	
			I _{OL} = 32 mA	4.5	_	0.8	
3-state output OFF-state leakage current	l _{OZ}	$V_{IN} = V_{IH}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5	_	±20	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±20	μΑ
Power-OFF leakage current	I _{OFF}	V _{IN} or V _{OUT} = 5.5 V		0		100	μΑ
Quiescent supply current	I _{CC}	V _{IN} = 5.5 V or GND		5.5	_	200	μΑ

Note: For devices with the ordering part number ending in J(CT.



9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PZL}		R _L = 500 Ω	1.8 ± 0.15	50	1.8	5.5	9.5	ns
				2.5 ± 0.2		1.2	3.7	5.8	
				3.3 ± 0.3		0.8	2.9	4.4	
				5.0 ± 0.5		0.5	2.3	3.5	
	t _{PLZ}		R _L = 500 Ω	1.8 ± 0.15	50	1.8	4.3	9.5	ns
				2.5 ± 0.2		1.2	2.8	5.8	
				3.3 ± 0.3		0.8	2.1	4.4	
				5.0 ± 0.5		0.5	1.4	3.5	
Input capacitance	C _{IN}		_	0 to 5.5	_	_	4	_	pF
Output capacitance	C _{OUT}		_	0 to 5.5	_	_	8	_	pF
Power dissipation	C_{PD}	(Note 1)	_	3.3	_	_	20		pF
capacitance				5.5		_	26		

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PZL}	R _L = 500 Ω	1.8 ± 0.15	50	1.8	10.5	ns
			2.5 ± 0.2		1.2	6.4	
			3.3 ± 0.3		0.8	4.8	
			5.0 ± 0.5		0.5	3.9	
	t _{PLZ}	R_L = 500 Ω	1.8 ± 0.15	50	1.8	10.5	ns
			2.5 ± 0.2		1.2	6.4	
			3.3 ± 0.3		0.8	4.8	
			5.0 ± 0.5		0.5	3.9	

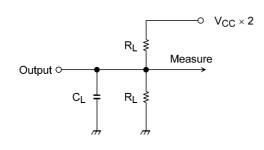
9.6. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 3 ns)

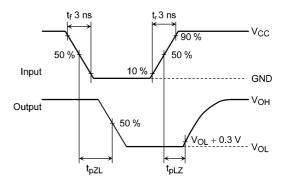
Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PZL}	R_L = 500 Ω	1.8 ± 0.15	50	1.8	12.0	ns
			2.5 ± 0.2		1.2	7.5	
			3.3 ± 0.3		0.8	5.5	
			5.0 ± 0.5		0.5	4.5	
	t _{PLZ}	R _L = 500 Ω	1.8 ± 0.15	50	1.8	12.0	ns
			2.5 ± 0.2		1.2	7.5	
			3.3 ± 0.3		0.8	5.5	
			5.0 ± 0.5]	0.5	4.5	

Note: For devices with the ordering part number ending in J(CT.



9.7. AC Characteristics Measurement Circuit and AC Waveform





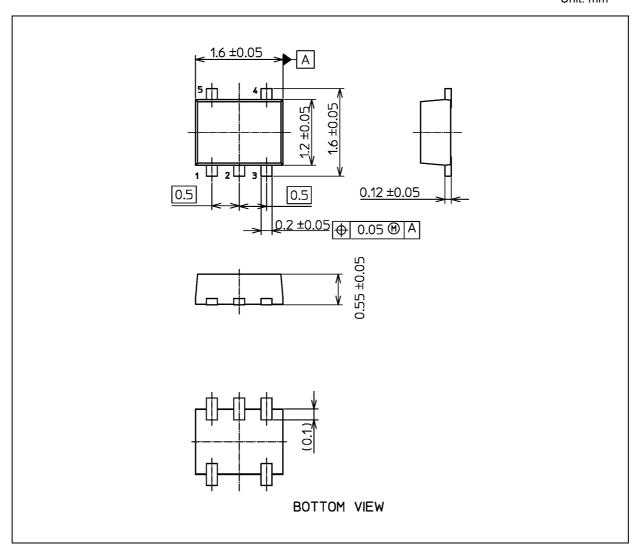
AC Characteristics Measurement Circuit

AC Waveform



Package Dimensions

Unit: mm



Weight: 3.0 mg (typ.)

	Package Name(s)	
Nickname: ESV		

Rev.3.0



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